

Quasi-particle Interference Effect in the Coulomb Blockade Problem

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Abstract

The Coulomb energy in a tunnel junction of very small capacitance, in which there are two or more kinds of quasi-particles, will involve coupling between pairs of quasi-particle species. The variation in the number of one of them will affect the motion of the others. This should be detectable in a current-biased experimental setup. Taking Josephson and single-electron tunnelling as an example, we calculate the Fourier coefficients of the voltage across the junction, which is a periodic function of time. We show that the interference effect is significant in that the frequency dependence of the Fourier coefficients is completely different from that associated with tunnelling of a single species.

1. Introduction

Tunnelling of charged quasi-particles through ultra-small junctions at low temperatures has received much attention lately (Averin and Likharev 1986; Ben-Jacob *et al.* 1988; Likharev 1988; Mullen *et al.* 1988). If there were more than one species of quasi-particle tunnelling through the ultra-small junction, they would be coupled through the Coulomb term ($Q^2/2C$) in the Hamiltonian of the system, Q being the sum of the quasi-particle charges, and C being the capacitance of the junction. The object of this note is to present an analysis of the interference effects arising out of the above coupling in a system consisting of two species of quasi-particles. A typical example of such a system would be a Josephson junction with a 'weak' link (Likharev 1979), in which single electrons and Cooper pairs can tunnel through. The analysis has obvious relevance to situations that involve the tunnelling of quasi-particles representing highly correlated states, such as those exhibiting fractional charges.

2. The Model Hamiltonian

We consider the situation in which there are two kinds of quasi-particles in the tunnel junction, carrying charges $Q_\alpha = \alpha e$ and $Q_\beta = \beta e$ and with tunnelling coefficients T_α and T_β respectively. The total charge in the junction is $Q = Q_\alpha + Q_\beta$. The Coulomb energy of the junction is equal to $(Q_\alpha + Q_\beta)^2/2C$.

The canonical coordinates (Ben-Jacob and Gefen 1985) conjugate to the number operators of the quasi-particles α and β are ϕ_α and ϕ_β respectively. Thus,

$$Q_\alpha = -i\alpha e \frac{\partial}{\partial \phi_\alpha}, \quad (1)$$

$$Q_\beta = -i\beta e \frac{\partial}{\partial \phi_\beta}. \quad (2)$$

The Hamiltonian has the form

$$H = -\frac{e^2}{2C} \left(\alpha \frac{\partial}{\partial \phi_\alpha} + \beta \frac{\partial}{\partial \phi_\beta} \right)^2 + T_\alpha \cos \phi_\alpha + T_\beta \cos \phi_\beta. \quad (3)$$

To solve the problem we make the variable changes

$$\phi = \frac{1}{2} \left(\frac{\phi_\alpha}{\alpha} + \frac{\phi_\beta}{\beta} \right), \quad (4)$$

$$\bar{\phi} = \frac{\phi_\alpha}{\alpha} - \frac{\phi_\beta}{\beta}, \quad (5)$$

so that

$$H = -\frac{e^2}{2C} \frac{\partial^2}{\partial \phi^2} + T_\alpha \cos[\alpha(\phi + \bar{\phi}/2)] + T_\beta \cos[\beta(\phi - \bar{\phi}/2)]. \quad (6)$$

Clearly, $\bar{\phi}$ is a constant of motion. It is now not difficult to solve for the eigenvalues.

We consider a simple case where the quasi-particle of type α provides the larger tunnelling current. The term in the Hamiltonian (6) that involves tunnelling of the quasi-particle of type β can then be treated by perturbation theory. The unperturbed Schrödinger equation is a Mathieu equation whose eigenvalues form an energy band E_k , and the corresponding eigenfunctions are Bloch functions,

$$\psi_k(\phi) = \exp(ik\phi) \sum_n c_{k,n} \exp(in\alpha\phi). \quad (7)$$

The first Brillouin zone has the range $-\alpha/2 < k < \alpha/2$, because the 'potential', i.e. the tunnelling term has a period of $2\pi/\alpha$. The tunnelling of the type β quasi-particle can be taken into account through perturbation theory. The term $T_\beta \cos[\beta(\phi - \bar{\phi}/2)]$ in (6) couples two Bloch states. Let the coupling matrix element be W_{lk} . Then

$$\begin{aligned} W_{lk} &\equiv \int \psi_l^*(\phi) T_\beta \cos[\beta(\phi - \bar{\phi}/2)] \psi_k(\phi) d\phi \\ &= \frac{T_\beta}{2} \sum_{m,n} c_{l,m}^* c_{k,n} [\exp(-i\beta\bar{\phi}) \delta_{k-l+(n-m)\alpha+\beta} + \exp(i\beta\bar{\phi}) \delta_{k-l+(n-m)\alpha-\beta}], \quad (8) \end{aligned}$$

where (7) has been used. Equation (8) is valid only when α and β are rational numbers. Hence α and β can be written in nonreducible form as n_1/n_2 and n_3/n_4 respectively with n_1, n_2, n_3 and n_4 being integers. The resulting energy band has a period μ/ν , where μ is the highest common factor of n_1 and n_3 , and ν is the lowest common multiple of n_2 and n_4 . The perturbed energy band can be found by diagonalising the matrix W , and the problem is thus solved. If, for simplicity, only one band is considered, then one has to solve the following secular equation:

$$\begin{vmatrix} E_k & W_{kl} \\ W_{lk} & E_l \end{vmatrix} = 0, \tag{9}$$

where k and l satisfy the relation given by (8). We shall give an example.

In a current-biased junction, the interaction Hamiltonian is

$$H_I = I\Phi/c, \tag{10}$$

where Φ is the flux. Since

$$\Phi_\gamma = \frac{\hbar c}{\gamma e} \phi_\gamma \tag{11}$$

for γ equal to either α or β , we have

$$\Phi = \Phi_\alpha + \Phi_\beta = \frac{2\hbar c}{e} \phi. \tag{12}$$

Hence

$$H_I = \frac{2\hbar I}{e} \phi, \tag{13}$$

which is completely analogous to the model Hamiltonian for describing the dynamics of a band electron in a uniform electric field (Shockley 1950). It is well known that in the latter case

$$\frac{ds}{dt} = \frac{F}{\hbar}, \tag{14}$$

where s is the crystal wavevector and F is the applied force. Therefore, in the Coulomb blockade problem,

$$\frac{dk}{dt} = \frac{2I}{e}. \tag{15}$$

As pointed out by Widom *et al.* (1982), the voltage V across the junction corresponds to the group velocity of a band electron in a crystal in a uniform field. It thus has the periodicity of the energy band in k -space. We expand it in a Fourier series,

$$V_k = \sum_n V_n \sin(2n\pi k/\xi), \tag{16}$$

where ξ is the size of the Brillouin zone, as indicated after equation (7). From (14) we find that the frequency of V_k is $4\pi I/e\xi$, whereas for tunnelling of type α quasi-particles only, the frequency is $2\pi I/e\alpha\xi_\alpha$. Note that $\xi_\alpha = 1$ is the size of the Brillouin zone if the tunnelling of type β quasi-particles is ignored in (3). Therefore the interference effect leading to a change of the periodicity of V should be observable at suitably low temperatures, where the noise level will not mask the effect (i.e. for $k_B T < e^2/2C$).

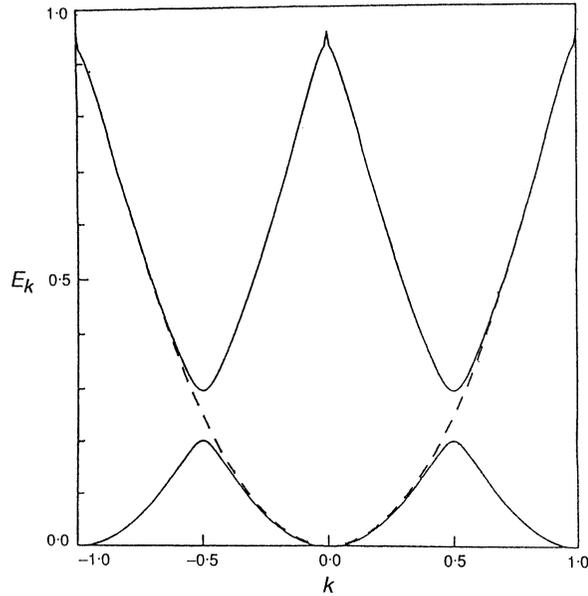


Fig. 1. Eigenvalues of the Hamiltonian (6) as a function of k . The dashed curve was evaluated under the conditions $\bar{\phi} = 0$, $e^2/2C : T_2 : T_1 = 1.0 : 0.3 : 0.0$. The lower and upper solid curves show E_k^- and E_k^+ as a function of k . They were calculated under the conditions $\bar{\phi} = 0$, $e^2/2C : T_2 : T_1 = 1.0 : 0.3 : 0.1$.

3. Discussion

We have applied the above ideas to the case of a Josephson junction, in which the two kinds of quasi-particles are the Cooper pairs with charge $2e$ and the unpaired electrons with charge e . In most experimental situations Josephson tunnelling produces a much larger current than that due to single-electron tunnelling. Thus we have $\alpha = 2$ and $\beta = 1$. In view of (8), the states $|k\rangle$ ($k > 0$) and $|k-1\rangle$ are coupled. From (9) we get

$$E_k^\pm = \frac{E_k + E_{k-1}}{2} \pm \sqrt{\frac{(E_k - E_{k-1})^2}{4} + |W_{k,k-1}|^2}. \quad (17)$$

After the coupling, the size of the first Brillouin zone is reduced to be in the range $0 < k < 1$. To show explicitly what has been derived, we have plotted in Fig. 1 the energy bands before and after coupling. The dashed curve is the lowest band without single-electron tunnelling. The lower and upper solid curves show E_k^- and E_k^+ as functions of k . These were calculated under the conditions that $\bar{\phi} = 0$ and $e^2/2C : T_2 : T_1 = 1 : 0.3 : 0.1$.

Table 1. Fourier coefficients of junction voltage [equation (16)]All V_j are normalised, with V_1 equal to unity

$(e^2/2C) : T_2 : T_1$	V_2	V_3	V_4
1.0:0.3:0.00 ^A	-0.481	0.305	-0.216
1.0:0.3:0.05 ^B	-0.474	0.291	-0.203
1.0:0.3:0.10 ^B	-0.436	0.229	-0.149
1.0:0.3:0.15 ^B	-0.402	0.170	-0.113

^A No single-electron tunnelling, V_j is the Fourier coefficient of the voltage at the frequency $j\pi I/|e|$.

^B Single-electron tunnelling included, V_j (from E_k^-) is the Fourier coefficient at the frequency $4j\pi I/|e|$.

In Table 1 we have listed the ratios of the Fourier coefficients of the junction voltage at different values of T_1 . According to the discussion above, if only Josephson tunnelling occurs, then the fundamental frequency of voltage oscillations is $\omega = \pi I/|e|$, and the coefficient V_j is associated with the oscillation of frequency $\omega_j = j\pi I/|e|$. If there is also single electron tunnelling, then $\omega = 4\pi I/|e|$, and the coefficient V_j is associated with the oscillation $\omega_j = 4j\pi I/|e|$. This distinction should be identifiable in experiments. The temperature should be low enough to quench the noise effectively, and, at the same time, should be in a range that would enable variation of the relative populations of the two quasi-particle species, i.e. close to T_c . Thus the preferred material for making a junction that would show this interference effect would be one that has a low T_c .

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References

- Averin, D. V., and Likharev, K. K. (1986). *J. Low Temp. Phys.* **62**, 345.
 Ben-Jacob, E., and Gefen, Y. (1985). *Phys. Lett. A* **108**, 289.
 Ben-Jacob, E., Gefen, Y., Mullen, K., and Schuss, Z. (1988). *Phys. Rev. B* **37**, 7400.
 Likharev, K. K. (1979). *Rev. Mod. Phys.* **51**, 101.
 Likharev, K. K. (1988). *IBM J. Res. Dev.* **32**, 144.
 Muller, K., Ben-Jacob, E., Jaklevic, R. C., and Schuss, Z. (1988). *Phys. Rev. B* **37**, 98.
 Shockley, W. (1950). 'Electrons and Holes in Semiconductors', Chs 7, 14 and 15 (Van Nostrand: New York).
 Widom, A., Megaloudis, G., Clark, T. D., Prance, H., and Prance, R. J. (1982). *J. Phys. A* **15**, 3887.

